

# PJD80N06

## 60V N-Channel Enhancement Mode MOSFET

**Voltage**

**60 V**

**Current**

**80 A**

### Features

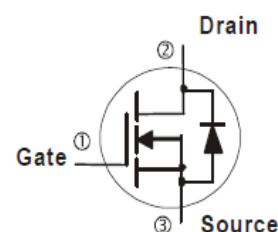
- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@20A < 7m\Omega$
- High switching speed
- Improved  $dv/dt$  capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case : TO-252 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0104 ounces, 0.297grams



TO-252



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	60	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$T_C=25^\circ\text{C}$	$I_D$	80	A
	$T_C=100^\circ\text{C}$		50	
Pulsed Drain Current (Note 1)	$T_C=25^\circ\text{C}$	$I_{DM}$	160	
Power Dissipation	$T_C=25^\circ\text{C}$	$P_D$	83	W
	$T_C=100^\circ\text{C}$		33	
Continuous Drain Current	$T_A=25^\circ\text{C}$	$I_D$	12	A
	$T_A=70^\circ\text{C}$		10	A
Power Dissipation	$T_A=25^\circ\text{C}$	$P_D$	2.0	W
Power Dissipation	$T_A=70^\circ\text{C}$		1.3	
Single Pulse Avalanche Energy (Note 6)		$E_{AS}$	135	mJ
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	$^\circ\text{C}$
Typical Thermal resistance (Note 4,5)	Junction to Case	$R_{\theta JC}$	1.5	$^\circ\text{C/W}$
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature



# PJD80N06

## Electrical Characteristics ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	60	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	2.0	3.0	4.0	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	5	7	mΩ
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =48V, V <sub>GS</sub> =0V	-	-	1.0	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±100	nA
Dynamic (Note 7)						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =48V, I <sub>D</sub> =25A, V <sub>GS</sub> =10V (Note 1,2)	-	104	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	33	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	26	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	6352	-	pF
Output Capacitance	C <sub>oss</sub>		-	380	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	134	-	
Turn-On Delay Time	td(on)	V <sub>DD</sub> =30V, I <sub>D</sub> =30A, V <sub>GS</sub> =10V, R <sub>G</sub> =3.3Ω (Note 1,2)	-	83	-	ns
Turn-On Rise Time	t <sub>r</sub>		-	184	-	
Turn-Off Delay Time	td(off)		-	203	-	
Turn-Off Fall Time	t <sub>f</sub>		-	113	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>	---	-	-	80	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.7	1.3	V

### NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature  $T_J(MAX)=150^{\circ}\text{C}$ . Ratings are based on low frequency and duty cycles to keep initial  $T_J=25^{\circ}\text{C}$ .
4. The maximum current rating is package limited.
5.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
6. The test condition is  $L=0.3mH, I_{AS}=30A, V_{DD}=25V, V_{GS}=10V$
7. Guaranteed by design, not subject to production testing.

# PJD80N06

## TYPICAL CHARACTERISTIC CURVES

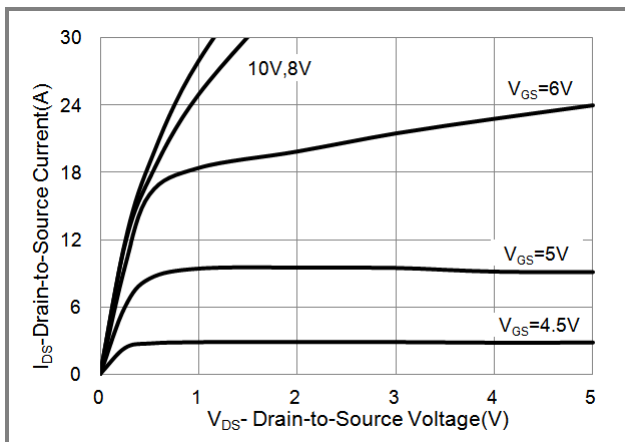


Fig.1 Output Characteristics

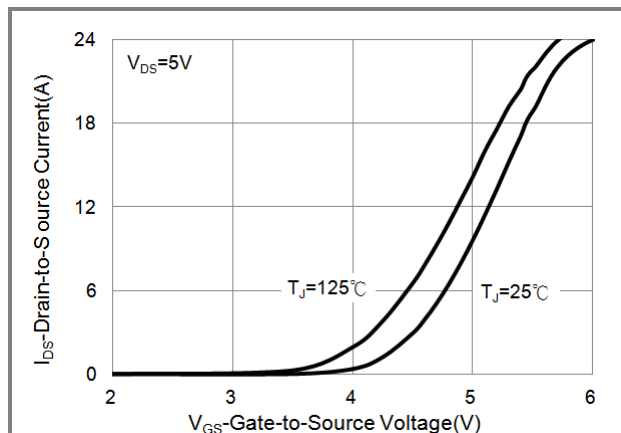


Fig.2 Transfer Characteristics

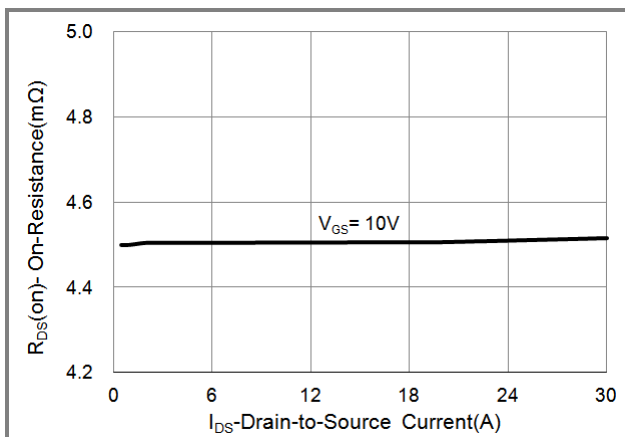


Fig.3 On-Resistance vs. Drain Current

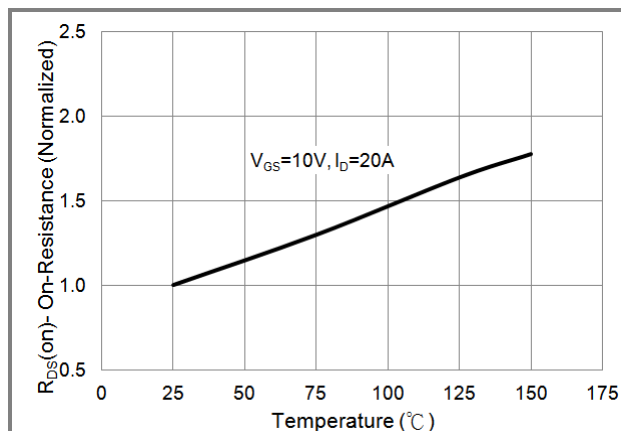


Fig.4 On-Resistance vs. Junction temperature

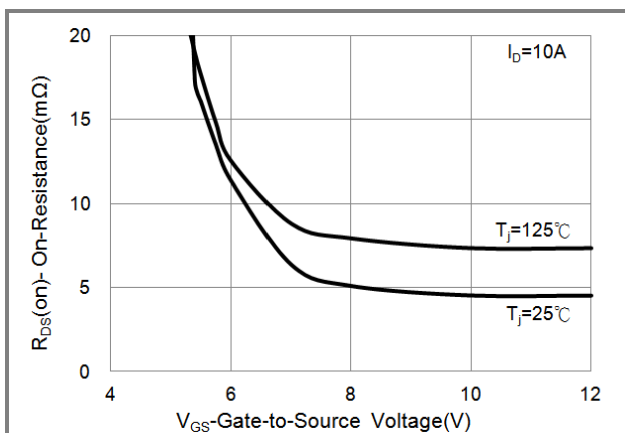


Fig.5 On-Resistance Variation with  $V_{GS}$ .

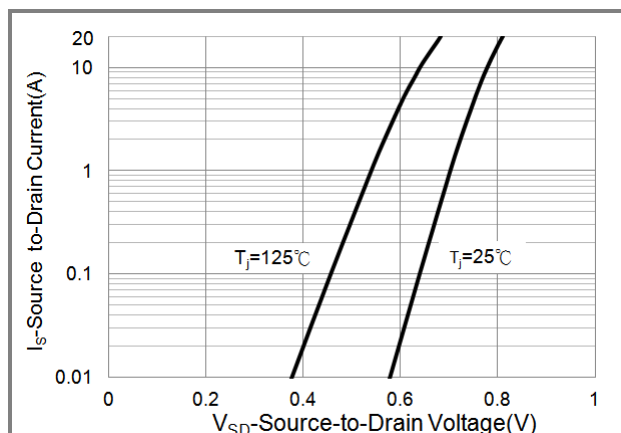


Fig.6 Source-Drain Diode Forward Voltage

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## TYPICAL CHARACTERISTIC CURVES

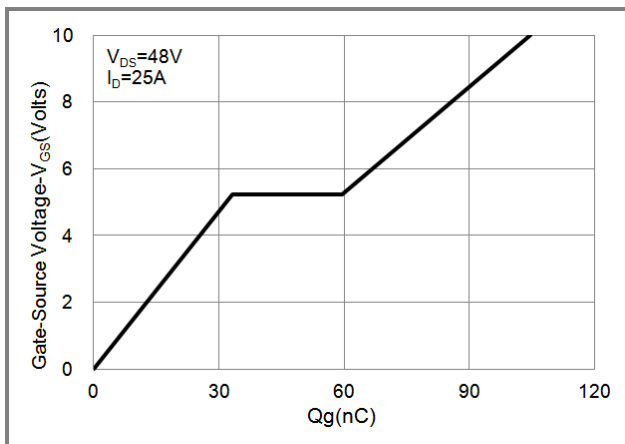


Fig.7 Gate-Charge Characteristics

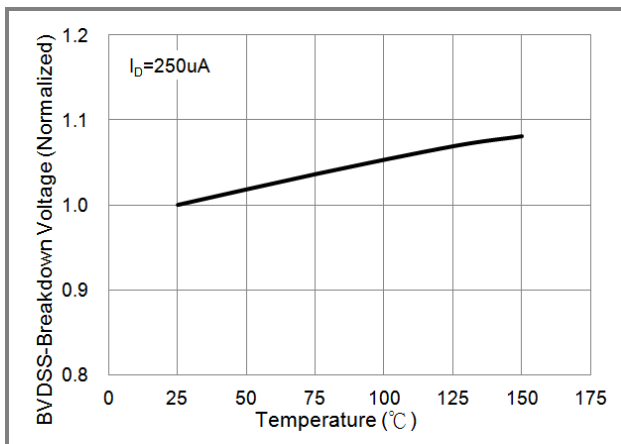


Fig.8 Breakdown Voltage Variation vs. Temperature

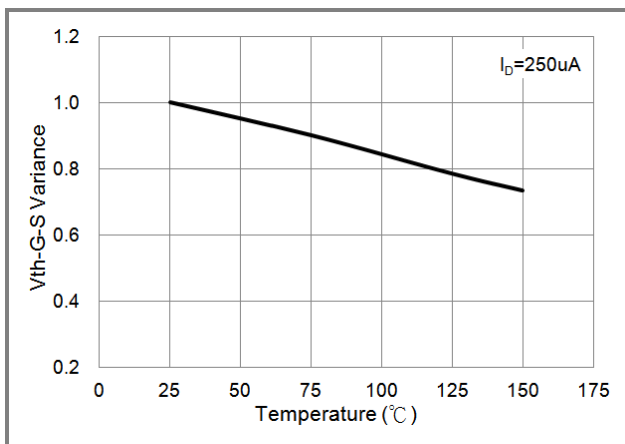


Fig.9 Threshold Voltage Variation with Temperature

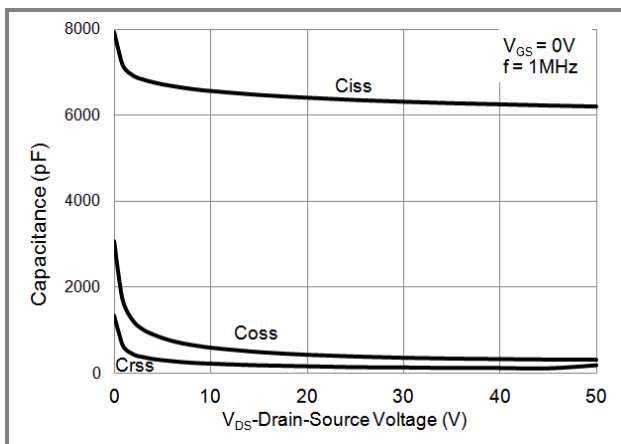


Fig.10 Capacitance vs. Drain-Source Voltage

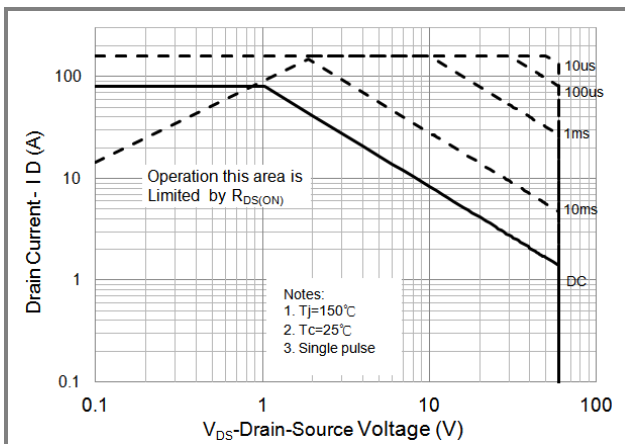


Fig.11 Maximum Safe Operating Area



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### TYPICAL CHARACTERISTIC CURVES

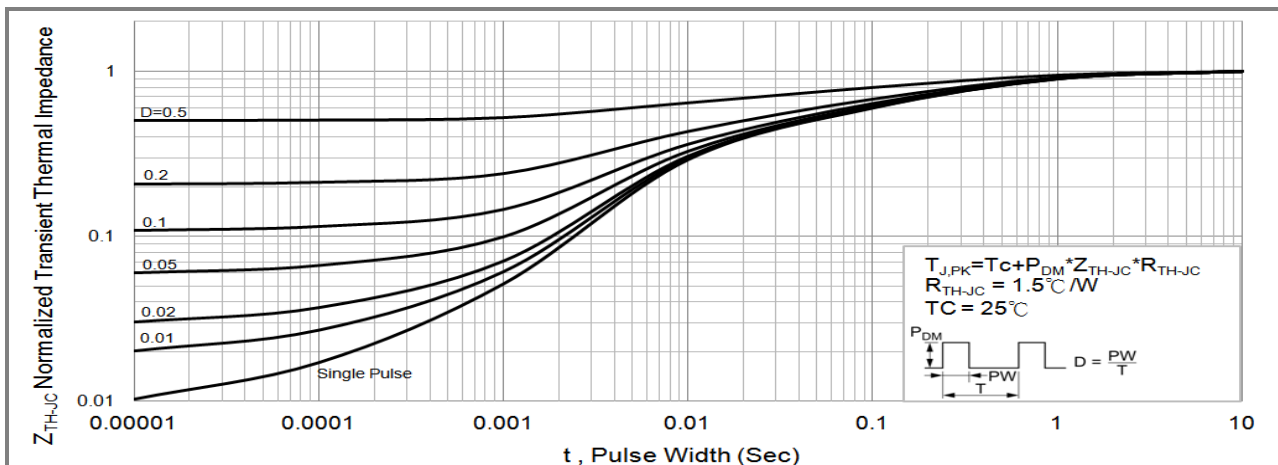
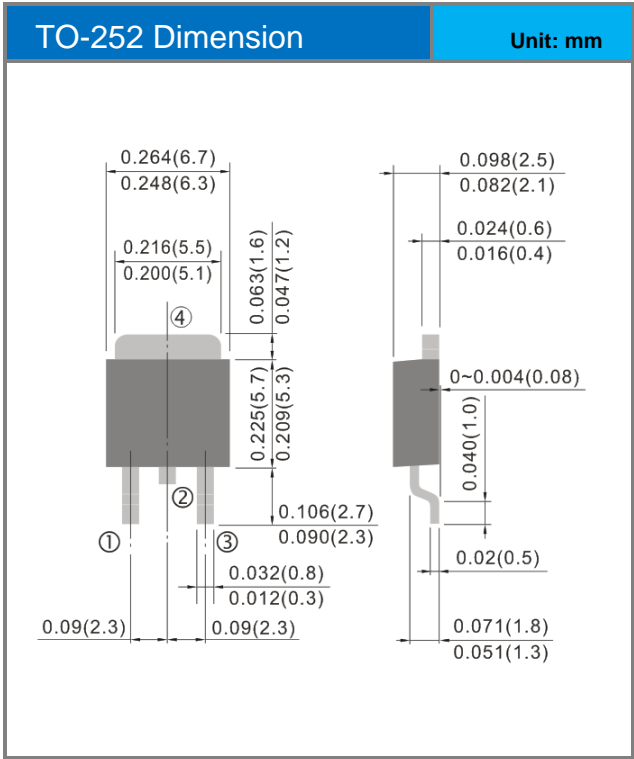


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width



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## Packaging Information

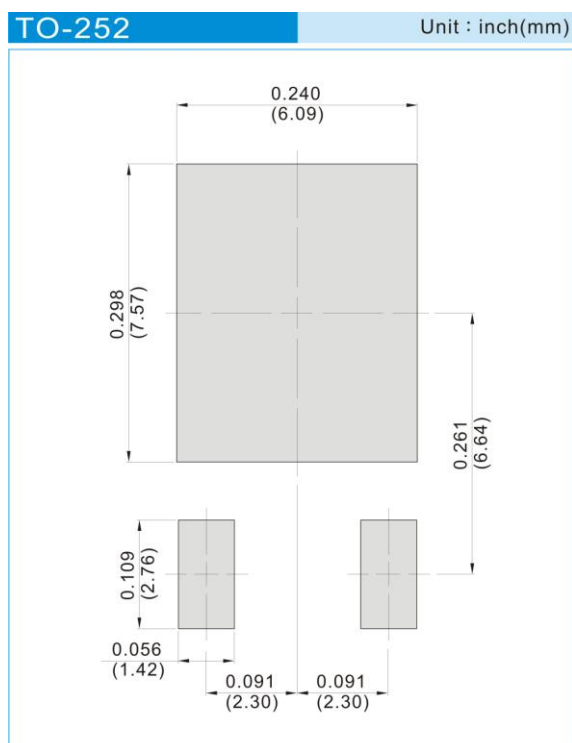


## PJD80N06

### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJD80N06_L2_00001	TO-252	3,000pcs / 13" reel	D80N06	Halogen free

### MOUNTING PAD LAYOUT





## PJD80N06

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